查询"3SK264-5"供应商



N-Channel Silicon MOSFET

3SK264

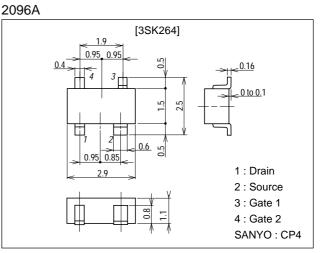
VHF Tuner, High-Frequency Amplifier Applications

Features

- \cdot Enhancement type.
- \cdot Easy AGC (Cut off at V_{G2S}\!=\!\!0V).
- \cdot Small noise figure.
- \cdot Excels in cross modulation characteristics.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DS}		15	V
Gate1-to-Source Voltage	V _{G1S}		±8	V
Gate2-to-Source Voltage	V _{G2S}		±8	V
Drain Current	۱ _D		30	mA
Allowable Power Dissipation	PD		200	mW
Channel Temperature	Tch		125	°C
Storage Temperature	Tstg		-55 to +125	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Voltage	V _{DS}	V _{G1S} =0V, V _{G2S} =0V, I _{DS} =100µA	15			V
Gate1-to-Source Cutoff Voltage	VG1S(off)	V _{DS} =6V, V _{G2S} =4V, I _D =100µA	0	0.7	1.3	V
Gate2-to-Source Cutoff Voltage	VG2S(off)	V _{DS} =6V, V _{G1S} =3V, I _D =100µA	0.1	0.9	1.6	V
Gate1-to-Source Leakage Current	IG1SS	V _{G1S} =±6V, V _{G2S} =V _{DS} =0V			±50	nA
Gate2-to-Source Leakage Current	I _{G2SS}	V _{G2S} =±6V, V _{G1S} =V _{DS} =0V			±50	nA
Zero-Gate Voltage Drain Current	IDSX	V _{DS} =6V, V _{G1S} =1.5V, V _{G2S} =4V	5.0*		24.0*	mA
Forward Transfer Admittance	yfs	V _{DS} =6V, I _D =10mA, V _{G2S} =4V, f=1kHz		17		mS
* : The 3SK264 is classified by I _{DSX} as follows : (unit : mA)		50 5 120 100 6 240	Continued on next pa			

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 I_{DSX} rank : 5, 6

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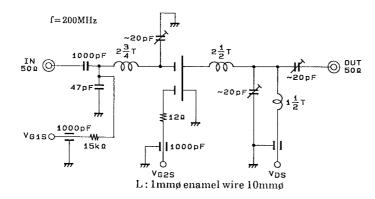
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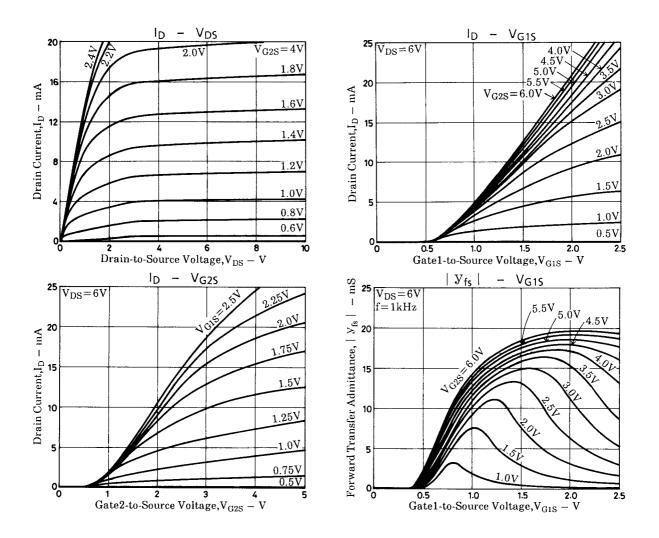
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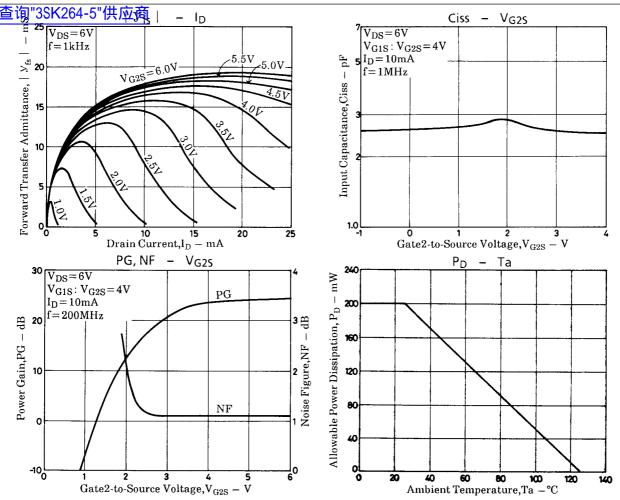
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Input Capacitance	Ciss	V _{DS} =6V, V _{G1S} =0V, V _{G2S} =4V, f=1MHz		2.5		pF
Reverse Transfer Capacitance	Crss	V _{DS} =6V, V _{G1S} =0V, V _{G2S} =4V, f=1MHz		0.015	0.03	pF
Power Gain	PG	V _{DS} =6V, I _D =10mA, V _{G2S} =4V, f=200MHz	20	23		dB
Noise Figure	NF	V_{DS} =6V, I _D =10mA, V _{G2S} =4V, f=200MHz		1.1	2.2	dB

PG, NF Specified Test Circuit







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